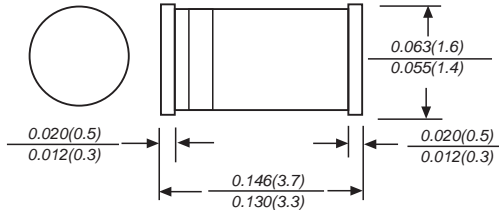


MINI MELF SWITCHING DIODES

Reverse Voltage - 100 Volts Forward Current - 0.15 Ampere

MINI MELF

Dimensions in inches and (millimeters)

FEATURES

- ◆ Fast Switching Device (TRR <4.0 nS)
- ◆ Power Dissipation of 500mW
- ◆ High Stability and High Reliability
- ◆ Low reverse leakage

MECHANICAL DATA

Case: MINI MELF Glass Case

Polarity: Color band denotes cathode end

Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**Maximum Ratings & Thermal Characteristics** (Ratings at 25 ambient temperature unless otherwise specified.)

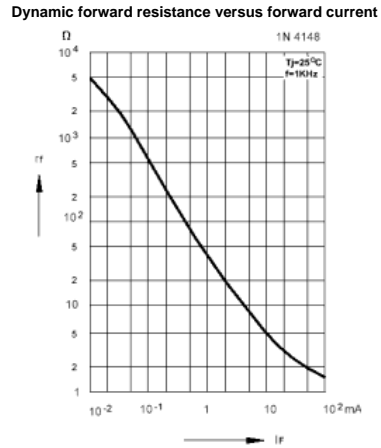
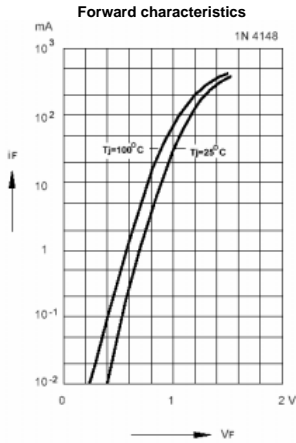
Parameters	Symbol	Value	Unit
Reverse Voltage	V _R	75	V
Peak Reverse Voltage	V _{RM}	100	V
Power Dissipation	P _d	500	mW
Operating junction temperature	T _j	175	
Storage temperature range	T _s	-65-+200	
Working Inverse Voltage	W _{IV}	75	V
Average Rectified Current	I _o	150	mA
Non-repetitive Peak Forward Current	I _{FM}	450	mA
Peak Forward Surge Current @tp=1s; TA=25	I _{FSM}	2.0	A

Valid provided that electrodes are kept at ambient temperature.

Electrical Characteristics (Ratings at 25 ambient temperature unless otherwise specified).

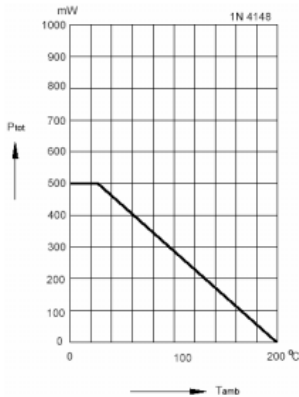
Symbols	Parameter	Test Condition	Limits		Unit
			Min	Max	
BV	Breakdown Voltage	IR=100uA IR=5uA	100 75		V
IR	Reverse Leakage Current	VR=20V VR=75	--- ---	25 5	nA uA
VF	Forward Voltage	LL4448 LL4148 LL4448	IF=5mA IF=10mA IF=100mA	0.62 --- 1 1	V
TRR	Reverse Recovery Time	IF= 10mA, IR=1.0mA RL=100Ω IRR=1mA	---	4	nS
C	Capacitance	VR=0V, f=1MHZ	---	4	pF

RATINGS AND CHARACTERISTIC CURVES LL4148

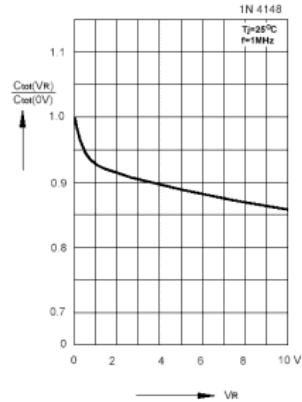


Admissible power dissipation versus ambient temperature

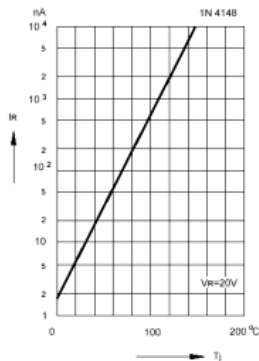
Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature



Relative capacitance versus reverse voltage



Leakage current versus junction temperature



Admissible repetitive peak forward current versus pulse duration

Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature

